NSN 5961-01-097-5530

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Inclosure Material:

Metal

Overall Length:

Between 0.060 inches and 0.085 inches

Terminal Length:

0.500 inches

Overall Diameter:

Between 0.209 inches and 0.230 inches

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

-70.0 collector to base voltage, dc and -60.0 collector to emitter voltage, dc and -6.0 emitter to base voltage, dc

Current Rating Per Characteristic:

30.00 milliamperes source cutoff current

Power Rating Per Characteristic:

1.2 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Test Data Document:

99974-7892302 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0